

TECHNICAL DATA

PART NUMBER: SCP-5988, Rev. A

THREE PHASE FULL WAVE BRIDGE RECTIFIER

DESCRIPTION: 1000 VOLT, 100 AMP THREE PHASE BRIDGE RECTIFIER ASSEMBLY.

Features:

- Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- Very High Surge Capacity
- Very suitable for medium frequency applications (upto 10 kHz)
- Soft Reverse Recovery at Low and High Temperature
- Trr guaranteed lower than 2.5 μsec

MAX. RATINGS / ELECTRICAL CHARACTERISTICS All ratings are at T_A = 25°C unless otherwise specified.

RATING	CONDITIONS	MIN	TYP	MAX	UNIT
Peak Inverse Voltage (PIV)	-	-	-	1100	V
Average DC Output Current (I _o)	$T_C = 55$ °C	-	-	100	Α
	T _C = 100 °C			70	
	T _C = 125 °C			55	
Peak Single Cycle Surge Current (I _{FSM})	t _p = 8.3 ms Single Half Cycle Sine Wave	-	-	720	A (pk)
Peak Recurring Surge Current (I _{FRM})	T _C = 25 °C	-	-	300	А
Max. Forward Voltage Drop V _{F1}	80A, Pulse, T _J = 25 °C	-	1.25	1.4	V
Max. Forward Voltage Drop V _{F2}	80A, Pulse, T _J = 125 °C	-	-	1.25	V
Max. Reverse Current I _{R1}	V _R = 1000V, Pulse, T _J = 25 °C	-	1.5	5.0	μΑ
Max. Reverse Current I _{R2}	V _R = 1000V, Pulse, T _J = 125 °C	=.	-	15	mA
Reverse Recovery Time T _{RR}	$I_F = 40A$; di/dt = 25A / μ s, $V_R = 100V$, $T_J = 25$ °C	-	1.6	2.1	μS
Reverse Recovery Current I _{RM}	$I_F = 40A$; di/dt = 25A / μ s, $V_R = 100V$, $T_J = 25$ °C	-	27	40	А
Max. Junction Capacitance C _T	$V_R = 30V, T_C = 25 ^{\circ}C$ $f_{SIG} = 1MHz, V_{SIG} = 100mV$	-	650	800	pF

Package Characteristics

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Max Module Power Loss at Rated Current $T_C = 55$ °C $T_C = 100$ °C	P _D	- -		350 185	W	
Thermal Resistance Junction to Case	R _{eJC}	-	-	0.35	°C/W	
Operating & Storage Temperature Range	T _{OP} & T _{STG}	- 55	-	150	оС	
Isolation – Pins to Base Plate	V _{iso}	-	-	1500	V	
Module Weight	М	-	165	-	gms	

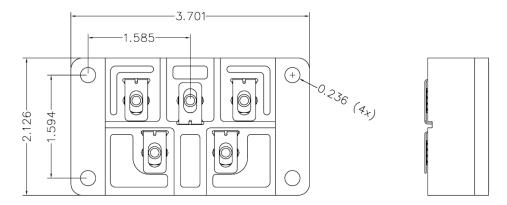
Note: Die Max Junction temperature is 190°C

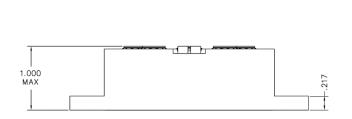
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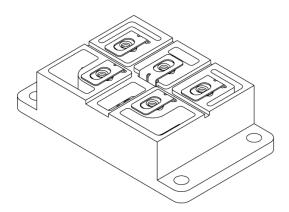
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MECHANICAL OUTLINE (DIMENSIONS ARE IN INCHES)







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